

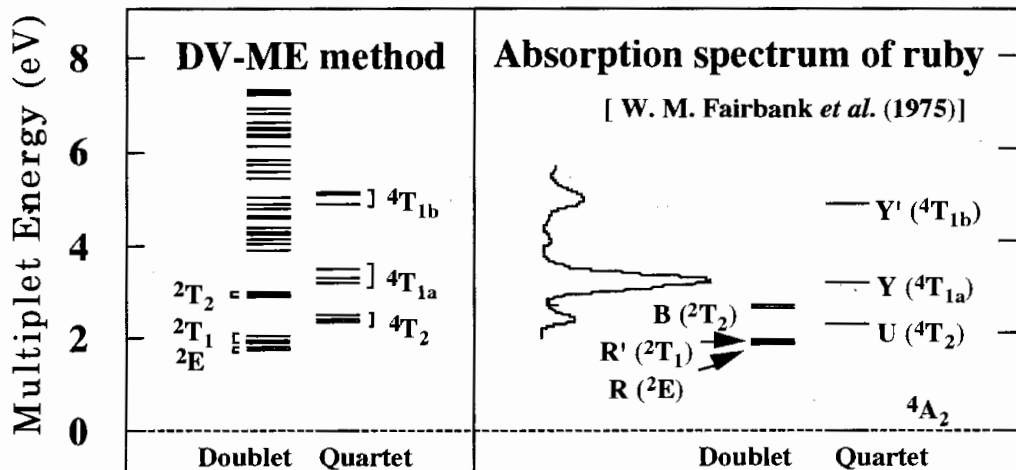
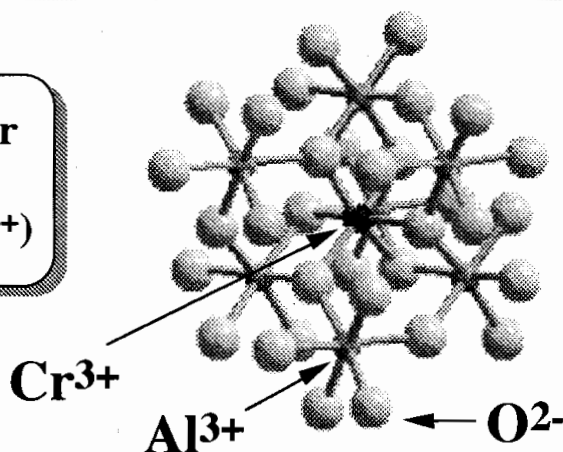
DV- $X\alpha$ 研究協會會報

Bulletin of the Society for Discrete Variational $X\alpha$

Vol. 11, No. 1 (1998)

Discrete Variational-Multielectron (DV-ME) method

Model cluster
of ruby
(α - $\text{Al}_2\text{O}_3:\text{Cr}^{3+}$)



DV-X α 研究協会会報

Bulletin of the Society for Discrete Variational X α

Vol. 11, No. 1 (1998)

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編集 DV-X α 研究協会

Korea-Japan DV-X a Joint Symposium('98)

11th DV-X a Annual Meetings

Abstracts

DVX a

Aug 3-5, 1998

at Hoam Faculty House

Seoul National University

Seoul, Korea

○ Organizations

Chairperson

H. Wakita Fukuoka University
S. J. Park Seoul National University
H. Kim Seoul National University

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K. Taniguchi Osaka Electro-Communication University, Japan

Supported by

KOSEF(Korea)
JSPS(Japan)

August 3 (Mon.)

10:00 - 11:00 Opening Ceremony

Chairperson: Hisamobu Wakita

Fine Ceramics in Japan and Korea, Hwan Kim, Seoul National University

Progress of DV-X α in Japan, Hirohiko Adachi, Kyoto University

Bridge between Korea and Japan in DV-X α , Myung Chul Chang, Kunsan National University

Research by DV-X α method in Japan,

Activity of the TANUKI meeting (the former "relativistic division")
Rika Sekine, Shizuoka University

11:00 - 11:40 "Clusters"

Chairperson: Tomoyuki Yamamoto

A1 Comparison of Boron with Aluminum Clusters

Kazuyoshi Adachi*, Rika Sekine, Shizuoka Univ.; and Jun Onoe, RIKEN

A2 Geometries and electronic structures of 3d-transition metal clusters

Ryuichi Kondo*, Kumiko Tanaka, and Rika Sekine, Dep. of Chemistry, Faculty of Sci., Shizuoka Univ.; Jun Onoe, Kazuo Takeuchi, Riken; and Hirohide Nakamatsu, Chemical Research Institute, Kyoto Univ.

A3 Electronic Structure of a Sandwich Cubane-Type Cluster with Molybdenum-Cadmium-Sulfur (Mo₃S₄Cd₄Mo₃) Core

Genta Sakane*, and Takashi Shibahara*, Department of Chemistry, Okayama University of Science; and Hirohiko Adachi, Department of Metallurgy, Kyoto University

A4 Local electronic states of oxygen vacancies in metal oxides
Makoto Azuma*, Shigeto R. Nishitani, Isao Tanaka, and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University

A5 Impurity states in ZnO ceramics by cluster calculations
Fumiyasu Oba*, Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University; and Isao Tanaka, Department of Energy Science and Technology, Kyoto University

Comment

11:40 - 13:10 Lunch

13:10-13:50 "Materials Science I"

Chairperson: Jun Yasui

A6 Nature of Chemical Bonding in Sulfur Fluorides
Kumiko Tanaka*, and Rika Sekine, Dep. of Chemistry, Faculty of Science, Shizuoka University; Jun Onoe, RIKEN; and Hirohide Nakamatsu, Chemical Research Institute, Kyoto Univ.

A7 Metal-Hydrogen Interactions in Hydrogen Storage Alloys
Kenichi Nakatsuka*, Hiroshi Yukawa and Masahiko Morinaga, Department of Materials Science and Engineering, Graduate School of Engineering, Nagoya University

A8 Electronic Structures of Hydrogen in Perovskite-type Oxide, SrZrO₃
M.Yoshino*, K.Nakatsuka, H.Yukawa and M.Morinaga, Department of Materials Science and Engineering, Graduate school of Engineering, Nagoya University

A9 Electronic structure and chemical bonding of T₂MTiS₂ (T₂=Cr, Fe) by cluster calculation
Yang-Soo Kim*, Isao Tanaka, and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University

A10 Electronic Structures of Polymorphous Phases in Perovskite-type Oxide, SrZrO₃
H.Yukawa*, M.Yoshino and M.Morinaga, Department of Materials Science and Engineering, Graduate school of Engineering, Nagoya University

A11 The electronic structures for ferroelectricity and antiferroelectricity
M. Fujita and S. Sugihara, Shonan Institute of Technology; and R. Sekine, Shizuoka University

A12 Electronic State of AgI-based Superionic Conducting Materials
Yoshiyuki Kowada* and Yoshinobu Yamadaa, Hyogo University of Teacher Education; and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University

Comment

13:50-14:20 Coffee Break

14:20 - 15:20 "Keynote Speech"

Chairperson: Rika Sekine

A13 Electronic Structures of Hydrogen Storage Alloys
M. Morinaga, Department of Materials Science and Engineering, Graduate School of Engineering, Nagoya University

15:20-16:00 "Dynamics" (Invited Speech)

Chairperson: Hyuryu Chang

A14 Calculation of Transition Probability for Nonadiabatic Process
Jun Yasui*, Toyobo Co. Ltd. Research Center

A15 New directions in X-ray emission and absorption spectroscopy with high brightness synchrotron radiation: Theoretical challenges
Rupert C.C. Perera, Center for X-ray Optics, Lawrence Berkeley National Laboratory, Berkeley, CA 94720, USA

Comment

16:00-16:20 Coffee Break

16:20 - 17:00 "Spectroscopy I"

Chairperson: Takahiro Kaneyoshi

A16 The effect of Ti 3d core-hole on Ti L-edge ELNES for SrTiO₃

Nobuki Hosoi*, Silicon Systems Research Laboratories, NEC Corporation

A17 Interpretation of Si-L_{2,3} edge electron energy loss near edge structure (ELNES) obtained from intergranular glassy film of Si₃N₄ ceramics.

Masato YOSHIDA*, Isao Tanaka, and H. Adachi, Kyoto University

A18 Core-hole Effects on B-K edge ELNES from Boron Nitride Polytypes

Hiroyuki Araki*, Isao Tanaka, Kazuyoshi Ogasawara, and Hirohiko Adachi, Kyoto University

August 4

A19 Fine Structure Analysis of X-ray Emission and Absorption Spectra of Low-Z Elements.

¹T.Yamamoto and ^{1,2}M.Uda, ¹Laboratory for Materials Science and Technology, Waseda University, ²Department of Materials Science and Engineering, Waseda University

A20 Theoretical analysis of O K α spectra

S. Sassa, T. Yamamoto and M. Uda, Department of Materials Science and Engineering, Waseda University, 3-4-1 Okubo, Tokyo 169-8555, Japan

A21 Theoretical analysis of K β X-ray spectrum emitted from third-row elements

K.Hayashi, T.Yamamoto and M.Uda, Department of Material Science and Engineering, Waseda University

A22 Theoretical analysis of O-K X-ray absorption and emission spectra of Cu oxides

H.Osawa, T.Yamamoto and M.Uda, Department of Materials Science and Engineering, Waseda University

17:00 Official Comment

17:10 - 21:00 Committee

17:10 - 21:00 Poster Session

9:00-9:10 Official Comment

9:10-10:10 "Keynote Speech"

Chairperson: Sunao Sugihara

B1 CRYSTAL STRUCTURE AND GRAPH

Su Jin Chung, School of Materials Science and Engineering, Seoul National University, Seoul 151-742, Korea

10:10-10:50 "Spectroscopy II"

Chairperson: Hyunju Chung

B2 A Structural Study of Dibromo(1,4,8,11-tetraazacyclotetradecane)copper(II) Complex in Crystal and in Aqueous Solution by X-ray Absorption Near Edge

Structure Measurements and DV-X α Calculations

Shuji Matsuo¹, Toshio Yamaguchi, and Hisanobu Wakita, Department of Chemistry, Fukuoka Univ.

B3 DV-X α Analysis of N-K XANES spectra for trans-[Ni(III) L Cl₂] and trans-[Cu(III) L Cl₂] (L=1,4,8,11-tetraazacyclotetradecane)

Kenji Koga, Satoshi Kurisaki, Toshio Yamaguti and Hisanobu Wakita, Department of Chemistry, Fukuoka Univ.

B4 A XANES study on the multinuclear transition metal complexes by a DV-X α analysis

Mitsutoshi Yokomizo¹, Tsutomu Kurisaki, Toshio Yamaguchi, and Hisanobu Wakita

Department of Chemistry, Faculty of Science, Fukuoka University

B5 A structural study on the analysis of Al-K X-ray Absorption Near Edge Structure for a series of Aluminosilicate minerals
Hikoshiro Ichihashi*, Satoshi Kurisaki*, Toshio Yamaguchi* and Hisanobu Wakita*, Department of Chemistry, Fukuoka Univ

B6 Calculation of Cu K-edge XANES for copper oxides
Minoru Ishizuka*, and Rika Sekine, Department of Chemistry, Faculty of Science, Shizuoka Univ.; and Hirohide Nakamatsu, Institute for Chemical Research, Kyoto Univ.

B7 F K Emission Spectra of Fluorides of Different Cation Coordinations
Sujin Kim and Sunja Park, School of Materials Science and Engineering, Seoul National University; Jun Kawai and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University

Comment

10:50 - 11:20 Coffee Break

11:20-11:40 "Invited Speech"

Chairperson: Masao Morishita

B8 Electronic structure of Ti_2O_7 using DV-X α cluster calculation method

Hyunju Chang* and J. D. Lee, Korea Research Institute of Chemical Technology, Taejeon, 305-600, Korea

Comment

B9 Application of DV-X α to the Firsov Model of Electronic Stopping Force in Slow Velocity Atomic Collisions
Masahiko KATO*, School of Engineering, Nagoya University

11:40-13:20 Lunch

13:20-13:50 "Surface"

Chairperson: Hiroshi Yukawa

B9 Relationship between Work Function of Metals and Stacking Faults
Y. Fujimoto, A. Nakamura and M. Uda, Dept. of Materials Science and Engineering, Waseda Univ. 3-4-1 Okubo, Shinjyuku-ku, Tokyo, 169-8555, Japan

B10 Initial oxidation and hydroxydation of Al exposed to wet air
M. Kawasaki, Y. Nakagawa and M. Uda, Department of Materials Science and Engineering, Waseda University, 3-4-1 Ohkubo, Tokyo 169-8555, Japan

B11 Theoretical analysis of the electronic structure in valence band of H-terminated Si(111)
Y. Ogyu, T. Yamamoto and M. Uda, Department of Materials Science and Engineering, Waseda University, 3-4-1 Okubo, Tokyo 169-8555, Japan

B12 Theoretical analysis of XPS spectrum of Al/Si interface
A. Hanta, K. Hirose*, T. Yamamoto and M. Uda, Department of Material Science and Engineering, Waseda University, Institute of Space and Astronautical Science

13:50-14:50 "Keynote speech"

Chairperson: Yoshiyuki Kawada

B13 Application of DV-X α calculations in ceramics science
Isao TANAKA, Department of Energy Science and Technology, Kyoto University

14:50-15:15 coffee break

15:15-15:50 "Materials Science II"

Chairperson: Yoshiyuki Kawada

- B14 Electronic State of Ca-doped BaTiO₃**
Myung Chul Chang, Department of Materials Science and Engineering,
Kunsan National University
- B15 Raman Spectrum of Ca-doped BaTiO₃**
Myung Chul Chang¹⁾, Soo-Chang Yu²⁾ ¹⁾Department of Materials Science
and Engineering, ²⁾Department of Chemistry, Kunsan National University
- B16 Theoretical Analysis of Bonding Interactions of the Nearest
V-H Bonds in Vanadium Monohydrate**
Hiroyuki T. Takeshita¹⁾, Hirohiko Adachi²⁾, Hideaki Tanaka¹⁾, Nobuhiro
Kuriyama¹⁾ and Itsuki Uehara,¹⁾ Osaka National Research Institute, AIST,
MITI,²⁾Department of Materials Science and Engineering, Kyoto University
- B17 Metal-metal bondings in p-block metal oxides**
Motoki Sone¹⁾, Hirohiko Adachi, Department of Material Science and
Engineering, Kyoto University; Isao Tanaka, Department of Energy
Science and Technology, Kyoto University; and Masataka Mizuno, Kobe
Steel Corporation
- B18 Chemical Bondings of Si segregated at grain boundaries in
MgO ceramics**
T. Mizoguchi¹⁾, S. Nagano, F. Oba, M. Yoshiya, I. Tanaka, and H. Adachi,
Department of Materials Science and Engineering, Kyoto University

15:50-16:10 "Relativistic effect"

Chairperson: Genia Sakane

- B19 Relativistic Density-Functional Calculation for the Electronic
Structure of Uranyl Nitrate**
Masaru Hirata¹⁾ and Turgut Bastug, Department of Materials Science,
Japan Atomic Energy Research Institute (JAERI); Rika Sekine,
Department of Chemistry, Faculty of Science, Shizuoka University; Jun
Onoe, The Institute of Physical and Chemical Research (RIKEN); Hirohide
Nakamatsu, Institute for Chemical Research, Kyoto University; and
Shoichi Tachimori, Department of Materials Science, JAERI
- B20 The Electronic Structure of Uranium Metal(3)**
Masayoshi Kurihara, Nikkanryo; Masaru Hirata, JAERI; Rika Sekine,
Shizuoka Univ.; Jun Onoe, RIKEN; and Hirohide Nakamatsu, Institute for
Chemical Research, Kyoto Univ.
- B21 Electronic Structure for Hydrated Lanthanide and Actinide Ions**
Rika Sekine¹⁾, Mai Shibukawa and Takahiro Hiroe, Dep. of Chemistry,
Faculty of Sci., Shizuoka Univ.; and Masaru Hirata and Turgut Bastug,
Dept. of Materials Science, JAERI
- Comment**
- 16:10-16:30 "Materials science by DV-X α III"**
Chairperson: Young Suk Kang
- B22 Haldane Gap System: Electronic Structure and Magnetic
Properties**
T. Ishii¹⁾, M. Kawahara, H. Hara, M. Kondo, H. Matsuzaka, and S.
Kitagawa, Department of Chemistry, Tokyo Metropolitan University

B23 Electronic structures of $\text{Li}_{1-x}\text{CoO}_2$ ($0 < x < 1$)
Yukinori Koyama¹ and Isao Tanaka, Department of Energy Science and Technology, Kyoto University; and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University

B24 Electronic Structure of Transparent Conductive InGaZnO_4 with an YbFeO_4 type Layered Structure
Masahiro Orita¹, Masataka Mizuno², Isao Tanaka³, Hirohiko Adachi²
¹R&D Center, HOYA Corporation

²Department of Materials Science and Engineering, Kyoto University

³Department of Energy Science and Technology, Kyoto University

9:00-9:10 Official Comment

9:10-9:50 "Spectroscopy III"

Chairperson: Jun Yasui

C1 X-ray Emission Spectra of β - CaN_4 Prepared by ECR Plasma Sputtering Method.
T. Kaneyoshi¹, H. Kohzaki, M. Motoyama, and Hyogo Prefectural Institute of Industrial Research; Y. Tani, Y. Aoi, and E. Kamijyo, Ryukoku University; and Y. Muramatsu, NTT Integrated Information & Energy Systems Laboratories

Comment

C2 Theoretical analysis of Oxygen-K XANES spectra of Al_2O_3 , Cr_2O_3 and Fe_2O_3
H. Kanno T.Yamamoto and M. Uda, Department of Materials Science and Engineering, Waseda University, 3-4-1 Okubo, Tokyo 169-8555, Japan

C3 Theoretical analysis of O-K XANES spectra of Alkaline-earth Metal Oxides
A. Kanai, T.Yamamoto and M.Uda, Department of Materials Science and Engineering, Waseda University, 3-4-1 Okubo, Tokyo 169-8555, Japan

C4 Theoretical analysis of O-K XANES spectra of MnO_2 and TiO_2
K. Akiyoshi, T.Yamamoto and M.Uda, Department of Materials Science and Engineering, Waseda University

C5 Theoretical XANES and Related Spectra
Hirohide Nakamatsu¹, Song Bin, Kazuo Taniguchi, Rika Sekine, Takeshi Mukoyama, Hirohiko Adachi, Kyoto University, Osaka Electro-Communication University, Shizuoka University

16:30 - 17:30 General meeting

17:30-18:30 Transportation(Hoam to Novotel Ambassador)

18:30 - 21:00 Banquet

C6 Analysis of O K α EPMA Spectrum of Glassy State SiO₂-Na₂O Binary Slag
Masao Morishita* and Koichiro Koyama, Faculty of Engineering, Himeji Institute of Technology; Tadayoshi Kikko, Graduate Student of Himeji Institute of Technology; Masahiko Morinaga, Department of Materials Science and Engineering, Nagoya University; and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University.

Comment

9:50-10:10 "Invited speech"

Chairperson: Masao Morishita

C7 Electronic States Calculations regarding the Role of Impurities on Ceramic Properties
Kimichika Fukushima*, Power and Industrial Systems R&D Center, Toshiba Corporation

10:10-10:30 "Materials Science IV"

Chairperson: Hiroshi Yukawa

C8 Electronic Structures of Metal doped Bi₂Te₃ and Thermoelectricity
Sunao Sugihara, Seiji Kawashima, Hiroaki Suzuki, Shonan Institute of Technology; and R.Sekine*, Dept. of Chemistry, Faculty of Science Shizuoka University

C9 Chemical bonding of transition metal disilicides

Shigeto R. Nishitani*, Department of Materials Science and Engineering, Kyoto University, Kyoto 606-8501, Japan; Masataka Mizuno, Kobe Steel Ltd., Takatsukadai 1-5-5, Nishi-ku, Kobe, 651-2271, Japan; Isao Tanaka, Department of Energy Science and Technology, Kyoto University, Kyoto, 606-8501, Japan; and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University, Kyoto 606-8501, Japan

C10 The electronic structures of graphite, fullerene, and their compounds.

Shinji KAWASAKI*, Fujio OKINO and Hidekazu TOUHARA, Faculty of Textile Science & Technology, Shinshu University; Ning LIU and Toyohisa NAKAJIMA, EPSON KOWA Corp.

10:30 - 11:00 coffee break

11:00-11:30 "Methodology"

Chairperson: Hirohide Nakamatsu

C11. Bond index and valency evaluation for DV-X α
Katsumi Nakagawa*, Canon Ecology Laboratory

C12 First-Principles Calculation of Multiplet Energy Including Electron Correlation Effects

Kazuyoshi Ogasawara*, Takugo Ishii and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University; and Isao Tanaka, Department of Energy Science and Technology, Kyoto University

C13 Effect of Low Symmetry on Multiplet structures

Yukiko Ito*, Takugo Ishii, Kazuyoshi Ogasawara, and Hirohiko Adachi, Kyoto University

C14 First-Principles Calculation of Multiplet Structure in Chromium Ions Doped

Laser Materials

Takugo Ishii*, Kazuyoshi Ogasawara, and Hirohiko Adachi, Department of Materials Science and Engineering, Kyoto University; and Isao Tanaka, Department of Energy Science and Technology, Kyoto University

11:30 Closing Ceremony

98 年年会報告書

Reports of Korea-Japan DV-X α Joint Symposium ('98) <11th DV-X α Annual Meeting>

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